



Product Summary

BV _{DSS}	Rds(on) Max	I _D Tc = +25°C (Note 7)
40V	3.7mΩ @ V _{GS} = 10V	100A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

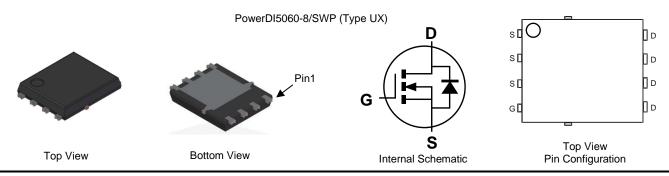
- Engine management systems
- Body control electronics
- DC-DC converters

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable
 and Robust End Application
- Low R_{DS(ON)} Minimizes Power Losses
- $\bullet \qquad \text{Low } \mathsf{Q}_g-\text{Minimizes Switching Losses}\\$
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
- https://www.diodes.com/quality/product-definitions/
- An automotive-compliant part is available under separate datasheet (<u>DMTH4005SPSWQ</u>)

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Orderable Part Number	Paakaga	Packing		
Orderable Part Number	Package	Qty.	Carrier	
DMTH4005SPSW-13	PowerDI5060-8/SWP (Type UX)	2500	Tape & Reel	

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Package limited.

Marking Information

Notes:



) | | = Manufacturer's Marking <u>H4005SS</u> = Product Type Marking Code <u>YY</u>WW = Date Code Marking <u>YY</u> = Year (ex: 24 = 2024) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	40	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current (Note 5)	T _A = +25°C T _A = +70°C	ID	20.9 17.5	A
Continuous Drain Current (Notes 6 & 7)	ID	100 100	A	
Maximum Continuous Body Diode Forward Current (Note 6)	ls	100	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ідм	320	А	
Avalanche Current, L = 0.6mH	I _{AS}	21	А	
Avalanche Energy, L = 0.6mH		Eas	132.3	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	57	°C/W	
Total Power Dissipation (Note 6) $T_{C} = +25^{\circ}C$		PD	150	W
Thermal Resistance, Junction to Case (Note 6)	Rejc	1	°C/W	
Operating and Storage Temperature Range		TJ, T _{STG}	-55 to +175	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

6. Thermal resistance from junction to soldering point (on the exposed drain pad).

7. Package limited.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

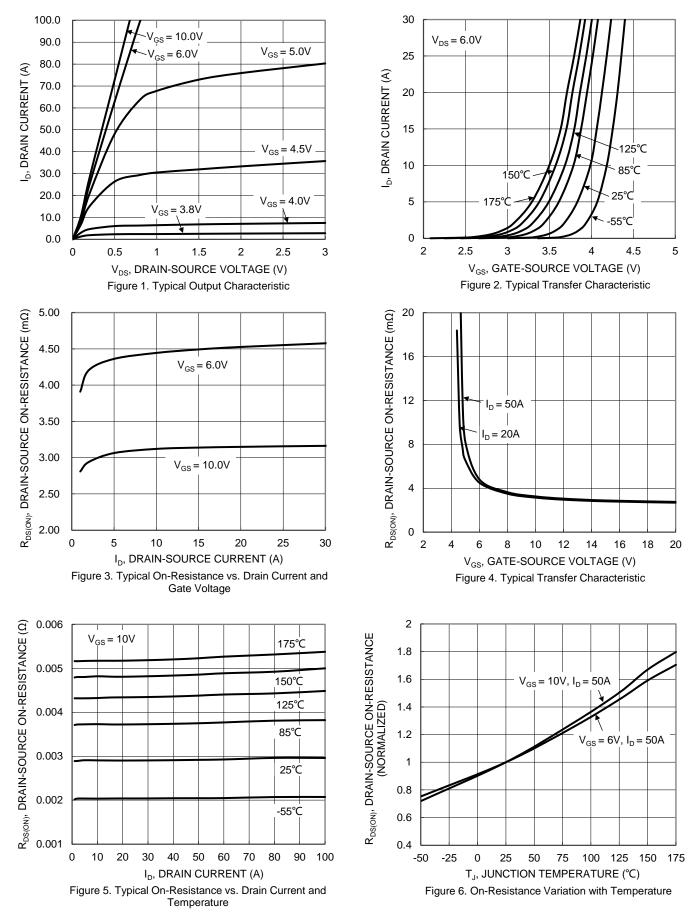
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	•						
Drain-Source Breakdown Voltage	BV _{DSS}	40	_	_	V	$V_{GS} = 0$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	—	—	1	μA	$V_{DS} = 32V, V_{GS} = 0$	
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	2	—	4	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	2.9	3.7	mΩ	$V_{GS} = 10V, I_D = 50A$	
Diode Forward Voltage	V _{SD}		0.88	_	V	$V_{GS} = 0, I_{S} = 50A$	
DYNAMIC CHARACTERISTICS (Note 9)	•						
Input Capacitance	Ciss		3062	_	pF	V _{DS} = 20V, V _{GS} = 0, f = 1MHz	
Output Capacitance	Coss	—	902.2	_			
Reverse Transfer Capacitance	Crss	_	179.2	_			
Gate Resistance	Rg	_	0.67	_	Ω	V _{DS} = 0, V _{GS} = 0, f = 1MHz	
Total Gate Charge	Qg	_	49.1	_			
Gate-Source Charge	Q _{gs}	_	10.3	_	nC	$V_{DD} = 20V, I_D = 50A,$ $V_{GS} = 10V$	
Gate-Drain Charge	Q _{gd}	_	13	_			
Turn-On Delay Time	t _{D(ON)}	_	8.7	_		$V_{DD} = 20V, V_{GS} = 10V,$ $I_D = 50A, R_G = 3\Omega$	
Turn-On Rise Time	t _R		6.8	_	ns		
Turn-Off Delay Time	t _{D(OFF)}		18.6	_			
Turn-Off Fall Time	tF		7.3	_			
Body Diode Reverse-Recovery Time	t _{RR}	_	31.8	—	ns		
Body Diode Reverse-Recovery Charge	Q _{RR}	_	26.5	—	nC	— I _F = 50A, di/dt = 100A/μs	

Notes: 8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.



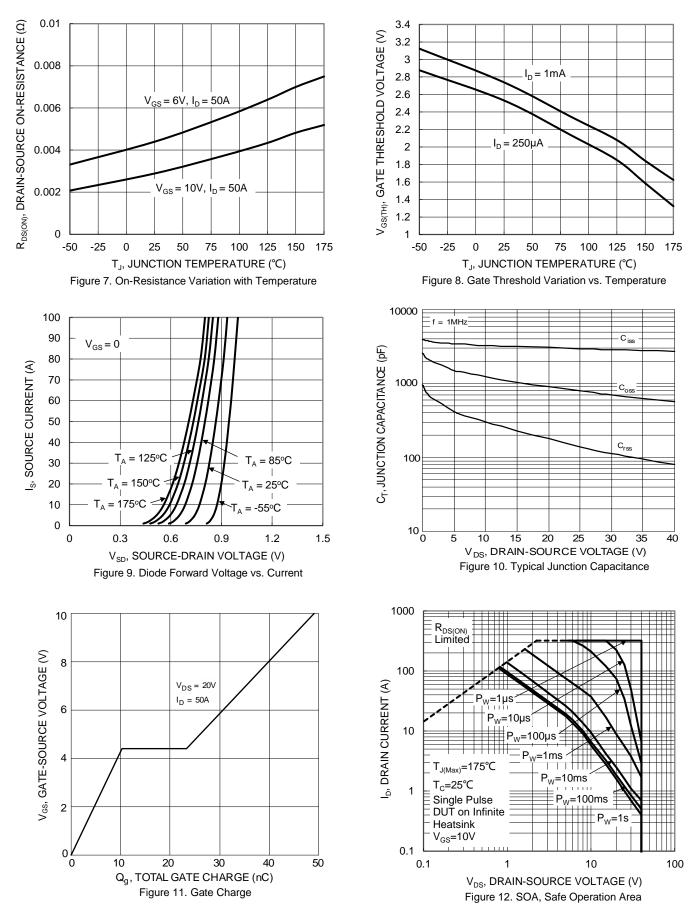
DMTH4005SPSW



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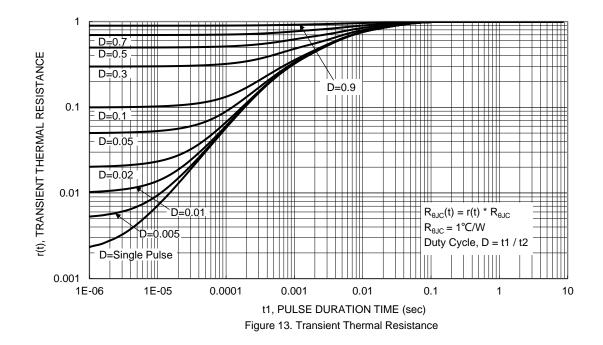


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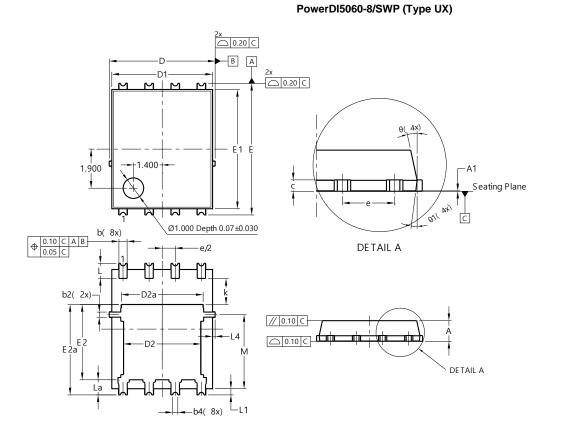






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

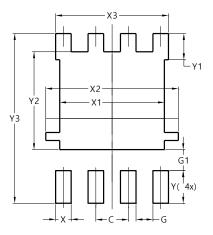


Po	PowerDI5060-8/SWP (Type UX)					
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0	0.05				
b	0.30	0.50	0.41			
b2	0.20	0.35	0.25			
b4	0.25REF					
С	0.230	0.330	0.277			
D	5	.15 BS0	2			
D1	4.70	5.10	4.90			
D2	3.56	3.96	3.76			
D2a	3.78	4.18	3.98			
E	6.40 BSC					
E1	5.60	6.00	5.80			
E2	3.46	3.86	3.66			
E2a	4.195	4.595	4.395			
е	1	.27BSC)			
k	1.05					
L	0.635	0.835	0.735			
La	0.635	0.835	0.735			
L1	0.200	0.400	0.300			
L4	0.025	0.225	0.125			
М	3.205	4.005	3.605			
θ	10°	12°	11°			
θ1	6°	8°	7°			
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	5.190		
X3	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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